



30V P-Channel Enhancement Mode MOSFET

Voltage -30 V Current -6.4A

Features

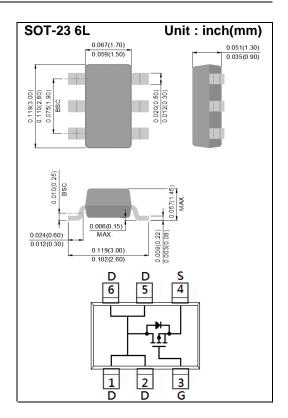
- R_{DS(ON)}, V_{GS}@-10V, I_D@-4A<32mΩ
- R_{DS(ON)}, V_{GS}@-4.5V, I_D@-2A<46mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: SOT-23 6L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0005 ounces, 0.014 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

| PARAMET | SYMBOL | LIMIT | UNITS | | |
|--|----------------------|-----------------|---------|-------|--|
| Drain-Source Voltage | | V _{DS} | -30 | V | |
| Gate-Source Voltage | V _{GS} | <u>+</u> 20 | | | |
| Continuous Drain Current(Note 4) | | I _D | -6.4 | A | |
| Pulsed Drain Current ^(Note 1,3) | | I _{DM} | -46 | | |
| Power Dissipation | T _a =25°C | P _D | 2 | W | |
| | Derate above 25°C | | 16 | mW/°C | |
| Operating Junction and Storage Temperature Range | | TJ,TSTG | -55~150 | °C | |
| Typical Thermal Resistance | R _{θJA} | | °C/W | | |
| - Junction to Ambient ^(Note 5) | | 62.5 | | | |





Electrical Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS | | |
|----------------------------------|---------------------|--|------|-------|--------------|-------|--|--|
| Static | | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _D =-250uA | -30 | - | - | V | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | V _{DS} =V _{GS} , I _D =-250uA | -1 | -1.6 | -2.5 | | | |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =-10V, I _D =-4A | - | 27 | 32 | mΩ | | |
| | | V _{GS} =-4.5V, I _D =-2A | - | 38 | 46 | | | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =-30V, V _{GS} =0V | - | - | -1 | uA | | |
| Gate-Source Leakage Current | I_{GSS} | V _{GS} = <u>+</u> 20V, V _{DS} =0V | - | - | <u>+</u> 100 | nA | | |
| Dynamic ^(Note 6) | | | _ | | | | | |
| Total Gate Charge | Q_g | V _{DS} =-15V, I _D =-5A, V _{GS} =-4.5V ^(Note 2,3) | - | 7.8 | - | nC | | |
| Gate-Source Charge | Q_gs | | - | 2.7 | - | | | |
| Gate-Drain Charge | Q_gd | | - | 2.8 | - | | | |
| Input Capacitance | Ciss | V _{DS} =-15V, V _{GS} =0V, f=1MHZ | - | 870 | - | pF | | |
| Output Capacitance | Coss | | - | 130 | - | | | |
| Reverse Transfer Capacitance | Crss | | - | 93 | - | | | |
| Turn-On Delay Time | td _(on) | $V_{DD}\text{=-}15V, I_{D}\text{=-}1A,$ $V_{GS}\text{=-}10V,$ $R_{G}\text{=}6\Omega^{(Note\ 2,3)}$ | - | 6.5 | - | ns | | |
| Turn-On Rise Time | tr | | - | 8.8 | - | | | |
| Turn-Off Delay Time | td _(off) | | - | 73 | - | | | |
| Turn-Off Fall Time | tf | | - | 44 | - | | | |
| Drain-Source Diode | | | | | | | | |
| Maximum Continuous Drain-Source | Is | | - | - | -2 | А | | |
| Diode Forward Current | IS | | | | | | | |
| Diode Forward Voltage | V_{SD} | I _S =-1A, V _{GS} =0V | | -0.75 | -1 | V | | |

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. Roja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing





TYPICAL CHARACTERISTIC CURVES

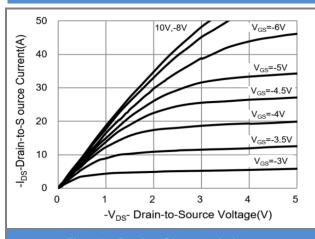


Fig.1 On-Region Characteristics

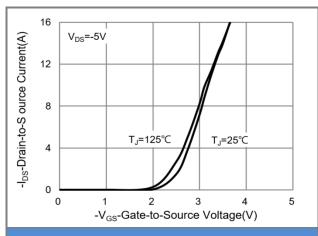


Fig.2 Transfer Characteristics

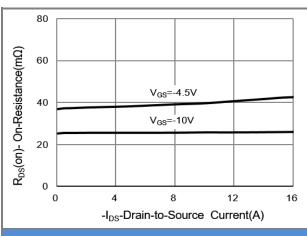


Fig.3 On-Resistance vs. Drain Current

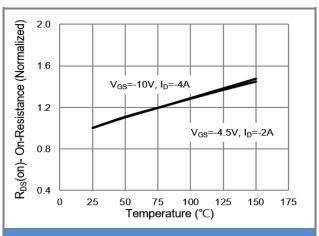
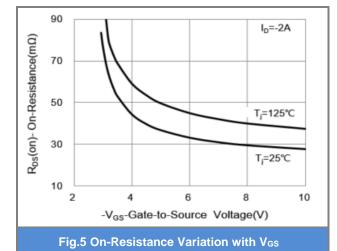


Fig.4 On-Resistance vs. Junction temperature



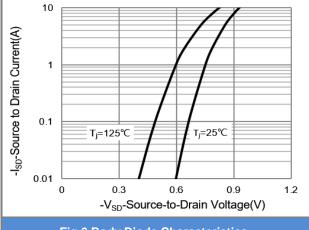


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

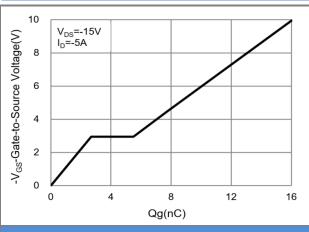


Fig.7 Gate-Charge Characteristics

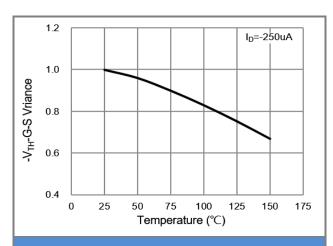


Fig.8 Threshold Voltage Variation with Temperature

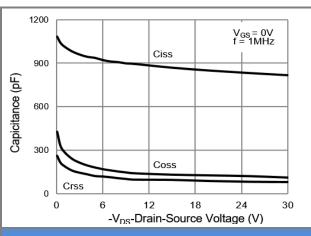


Fig.9 Capacitance vs. Drain-Source Voltage

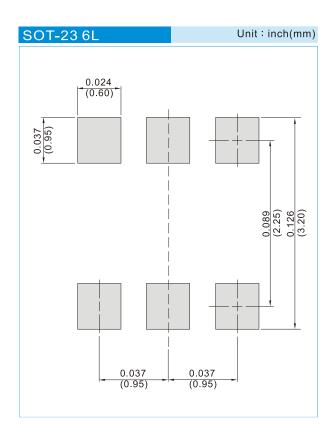




Part No. Packing Code Version

| Part No. Packing Code | Package Type | Packing Type | Marking | Version |
|-----------------------|--------------|------------------|---------|--------------------------------|
| PJS6403_S1_00001 | SOT-23 6L | 3K pcs / 7" reel | S03 | Halogen free RoHS compliant |

Mounting Pad Layout







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DMN1006UCA6-7 DMN16M9UCA6-7 STF5N65M6 IRF40H233XTMA1 IPSA70R950CEAKMA1 IPSA70R2K0CEAKMA1 STU5N65M6

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